

First measurements with silicon detectors irradiated above 3×10^{17} n/cm²

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Silicon detectors were recently irradiated with reactor neutrons up to fluence of 3×10^{17} n/cm². The irradiated samples include detectors previously irradiated with 1.6×10^{17} n/cm² so these were exposed to total of 4.6×10^{17} n/cm². Measurements have just started and first results will be presented in this contribution.

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